Vishay Semiconductors



Silicon NPN Phototransistor, RoHS Compliant



DESCRIPTION

BPV11F is a silicon NPN phototransistor with high radiant sensitivity in black, T-1¾ plastic package with base terminal and daylight blocking filter. Filter bandwidth is matched with 900 nm to 950 nm IR emitters.

FEATURES

Package type: leadedPackage form: T-1¾

• Dimensions (in mm): Ø 5

· High radiant sensitivity

Daylight blocking filter matched with 940 nm emitters

· Fast response times

• Angle of half sensitivity: $\varphi = \pm 15^{\circ}$

· Base terminal connected

 Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC



Detector for industrial electronic circuitry, measurement and control

PRODUCT SUMMARY				
COMPONENT	I _{ca} (mA)	φ (deg)	λ _{0.5} (nm)	
BPV11F	9	± 15	900 to 980	

Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
BPV11F	Bulk	MOQ: 3000 pcs, 3000 pcs/bulk	T-1¾	

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Collector base voltage		V _{CBO}	80	V
Collector emitter voltage		V _{CEO}	70	V
Emitter base voltage		V _{EBO}	5	V
Collector current		I _C	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA
Power dissipation	T _{amb} ≤ 47 °C	P _V	150	mW
Junction temperature		Tj	100	°C
Operating temperature range		T _{amb}	- 40 to + 100	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature	$t \le 5 \text{ s}, 2 \text{ mm from body}$	T _{sd}	260	°C
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm ²	R _{thJA}	350	K/W

Note

T_{amb} = 25 °C, unless otherwise specified





RoHS



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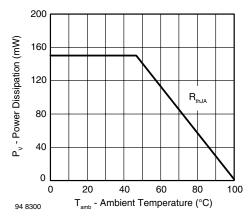


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	I _C = 1 mA	V _{(BR)CEO}	70			V
Collector emitter dark current	V _{CE} = 10 V, E = 0	I _{CEO}		1	50	nA
DC current gain	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA}, E = 0$	h _{FE}		450		
Collector emitter capacitance	V _{CE} = 0 V, f = 1 MHz, E = 0	C _{CEO}		15		pF
Collector base capacitance	V _{CE} = 0 V, f = 1 MHz, E = 0	C _{CBO}		19		pF
Collector light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm},$ $V_{CB} = 5 \text{ V}$	I _{ca}	3	9		mA
Angle of half sensitivity		φ		± 15		deg
Wavelength of peak sensitivity		λ_{p}		930		nm
Range of spectral bandwidth		λ _{0.5}		900 to 980		nm
Collector emitter saturation voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm},$ $I_C = 1 \text{ mA}$	V _{CEsat}		130	300	mV
Turn-on time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t _{on}		6		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t _{off}		5		μs
Cut-off frequency	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	f _c		110		kHz

Note

T_{amb} = 25 °C, unless otherwise specified

BASIC CHARACTERISTICS

 T_{amb} = 25 °C, unless otherwise specified

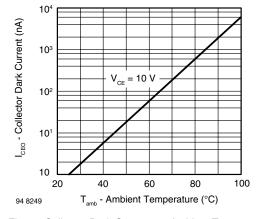


Fig. 2 - Collector Dark Current vs. Ambient Temperature

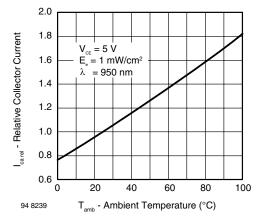


Fig. 3 - Relative Collector Current vs. Ambient Temperature

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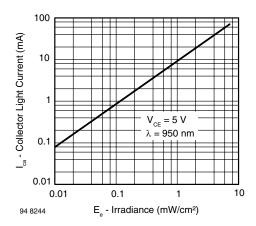


Fig. 4 - Collector Light Current vs. Irradiance

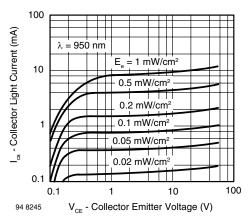


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

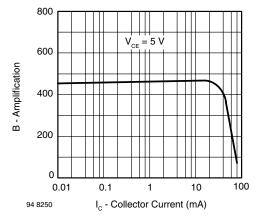


Fig. 6 - Amplification vs. Collector Current

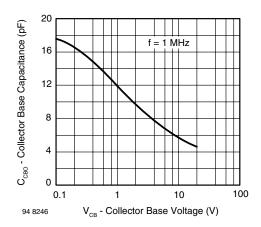


Fig. 7 - Collector Base Capacitance vs. Collector Base Voltage

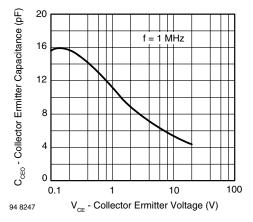


Fig. 8 - Collector Emitter Capacitance vs. Collector Emitter Voltage

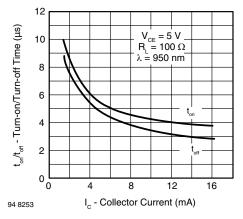


Fig. 9 - Turn-on/Turn-off Time vs. Collector Current



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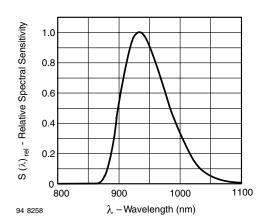


Fig. 10 - Relative Spectral Sensitivity vs. Wavelength

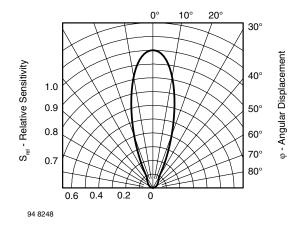
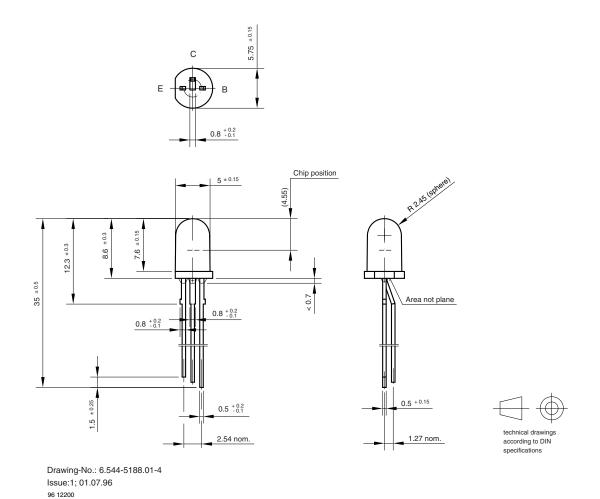


Fig. 11 - Relative Radiant Sensitivity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters







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